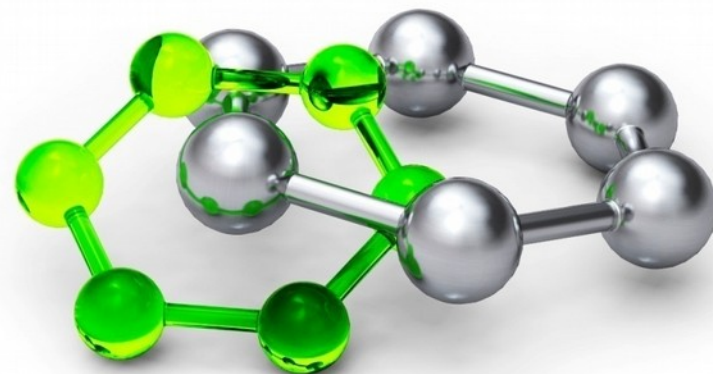




Středoevropský technologický institut
BRNO | ČESKÁ REPUBLIKA

S1007 Doing structural biology with the electron microscope

Lecture 3: Electron Microscope

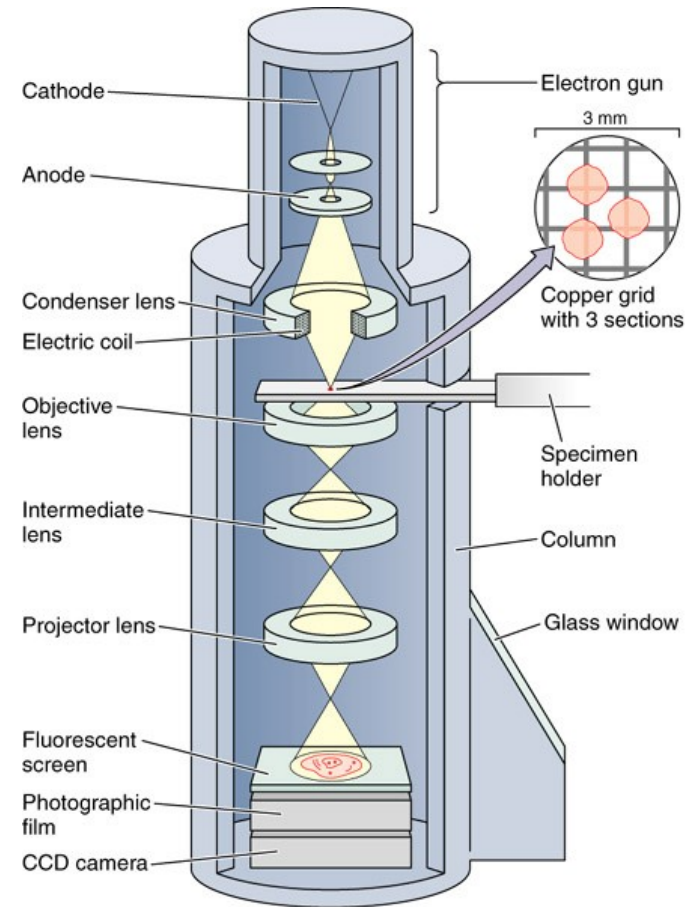


EVROPSKÁ UNIE
EVROPSKÝ FOND PRO REGIONÁLNÍ ROZVOJ
INVESTICE DO VAŠÍ BUDOUCNOSTI

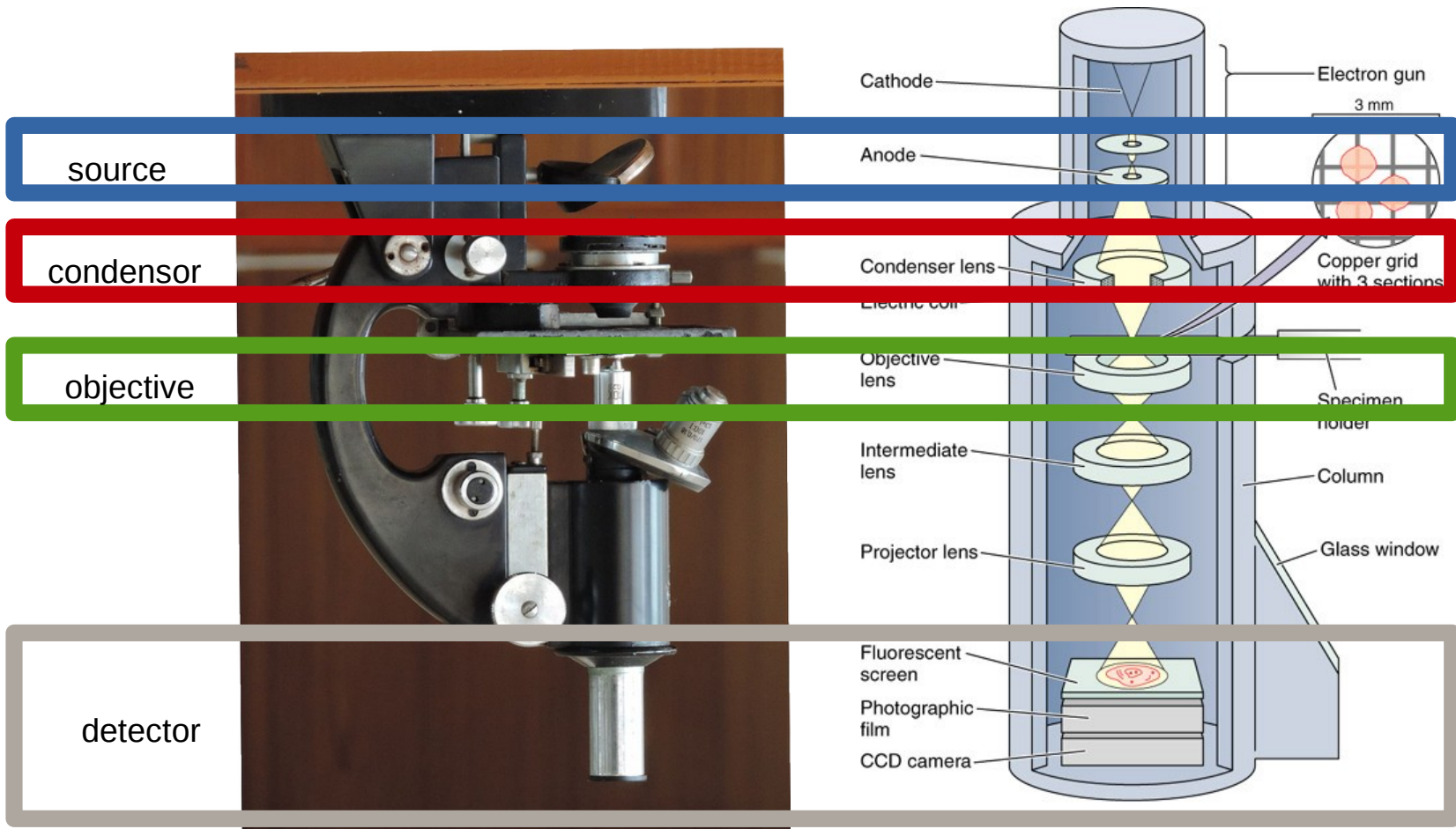


OP Výzkum a vývoj
pro inovace

Optical vs. TEM microscope

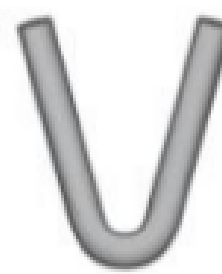


Optical vs. TEM microscope



Electron source

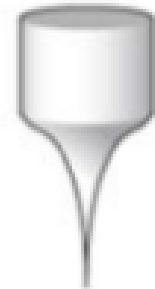
- tungsten filament
- LaB6 crystal
- Field Emission Gun



W filament
(a)



LaB₆
(b)



FEG
(c)

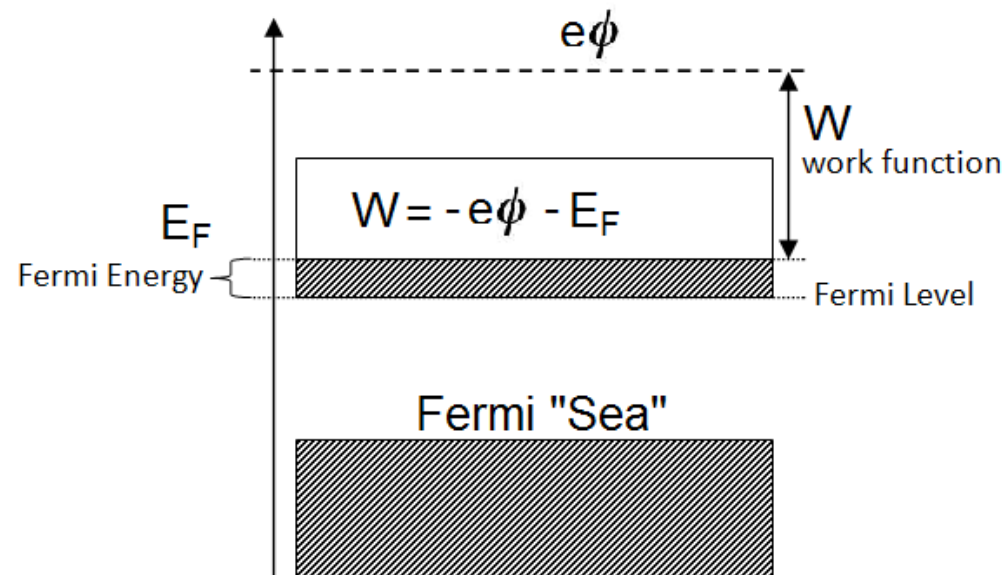


Probe size

Work function

$$W = -e\phi - E_F$$

$$\phi = V - \frac{W}{e}$$

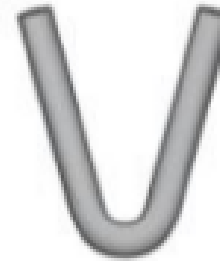


Electron source

- tungsten filament

- LaB6 crystal

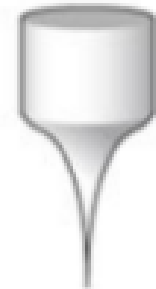
- Field Emission Gun



W filament
(a)



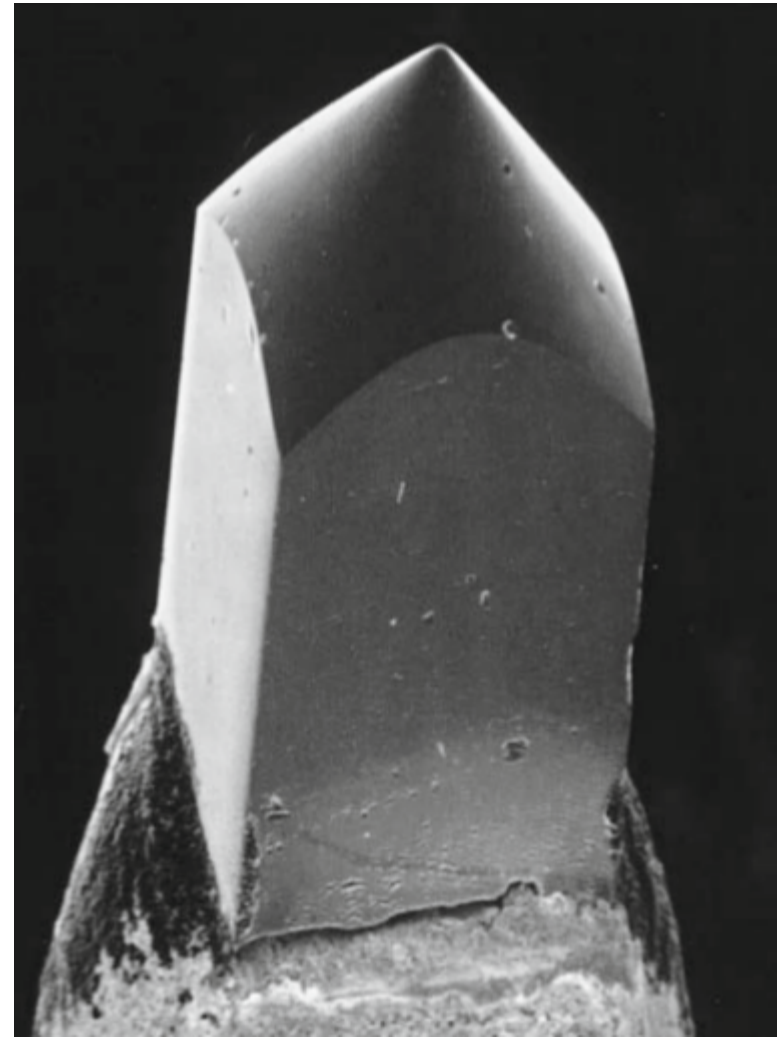
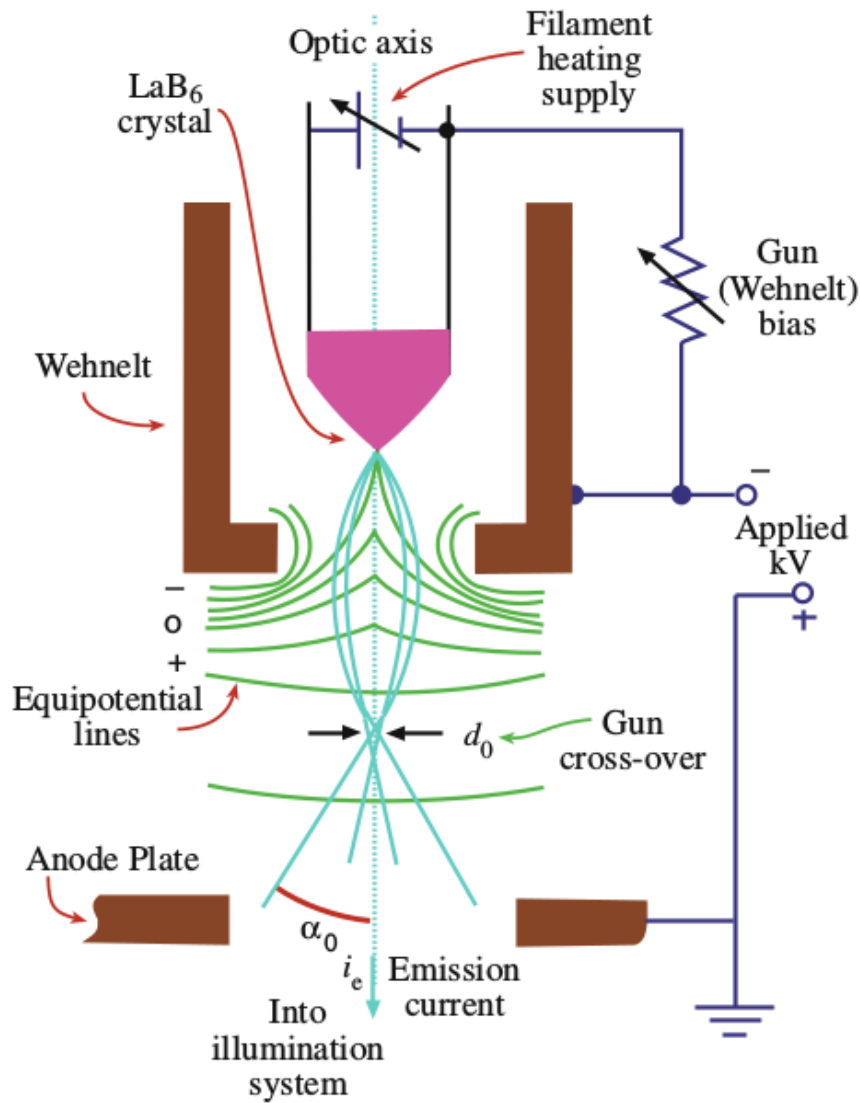
LaB₆
(b)



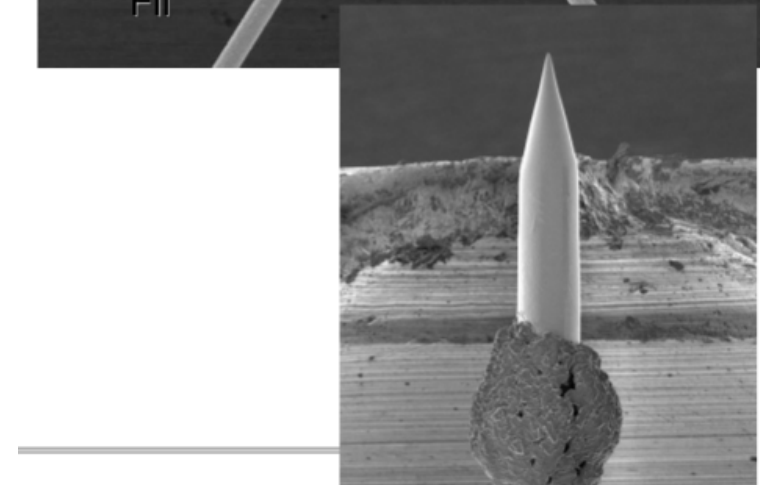
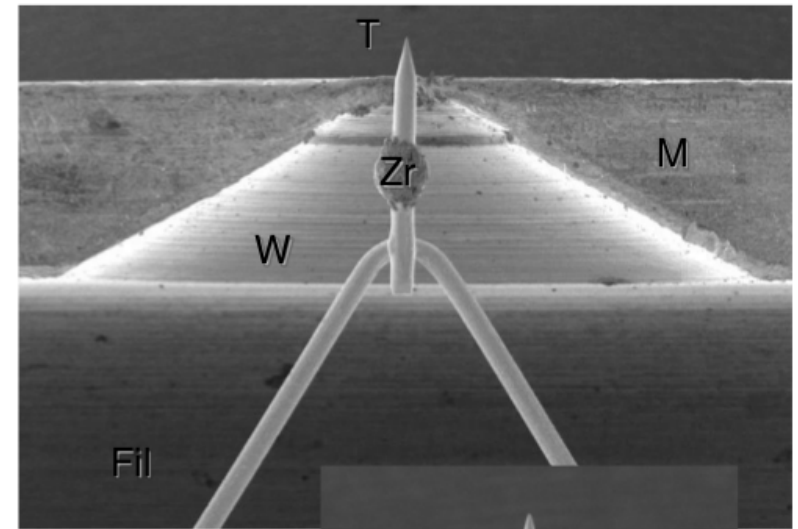
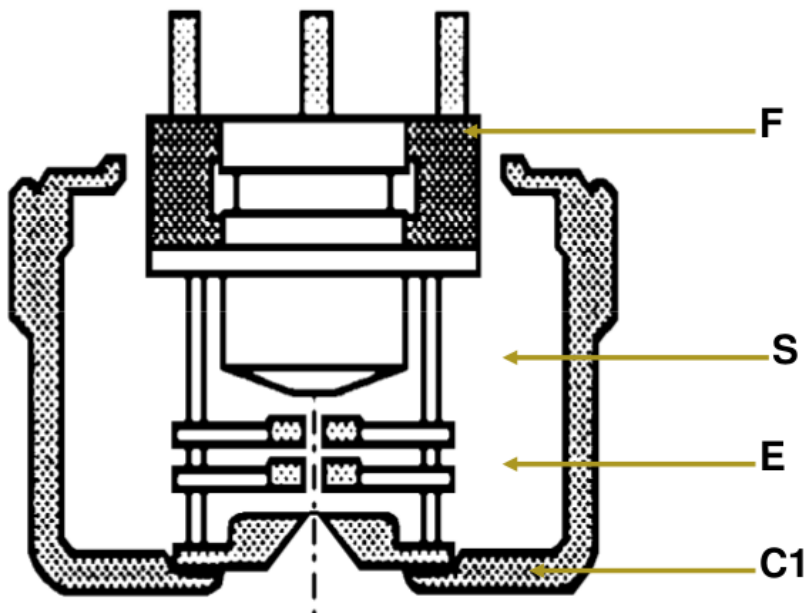
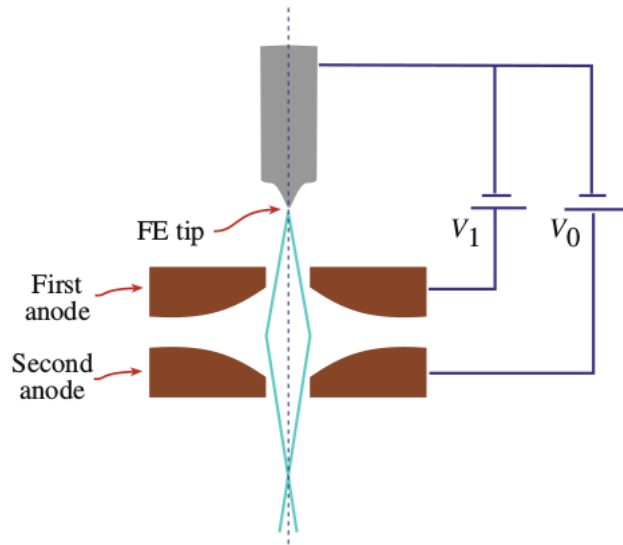
FEG
(c)

	Units	Tungsten	LaB ₆	Schottky FEG	Cold FEG
Work function, Φ	eV	4.5	2.4	3.0	4.5
Richardson's constant	A/m ² K ²	6×10^9	4×10^9		
Operating temperature	K	2700	1700	1700	300
Current density (at 100 kV)	A/m ²	5	10^2	10^5	10^6
Crossover size	nm	$> 10^5$	10^4	15	3
Brightness (at 100 kV)	A/m ² sr	10^{10}	5×10^{11}	5×10^{12}	10^{13}
Energy spread (at 100 kV)	eV	3	1.5	0.7	0.3
Emission current stability	%/hr	<1	<1	<1	5
Vacuum	Pa	10^{-2}	10^{-4}	10^{-6}	10^{-9}
Lifetime	hr	100	1000	>5000	>5000

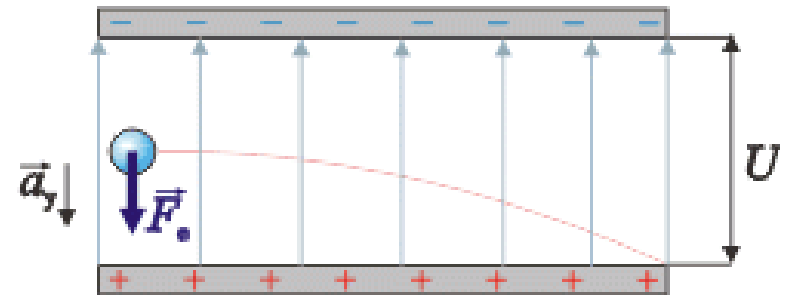
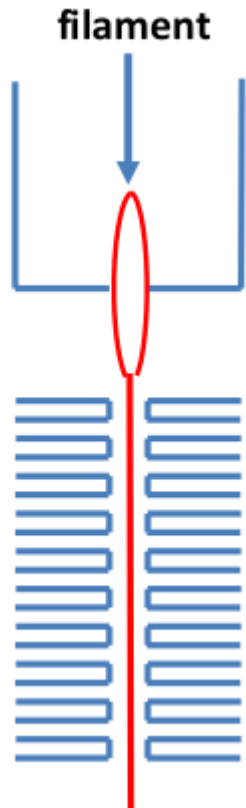
Electron source - LaB6



Electron source - FEG



Electron source - accelerator



$$E = U \cdot e$$

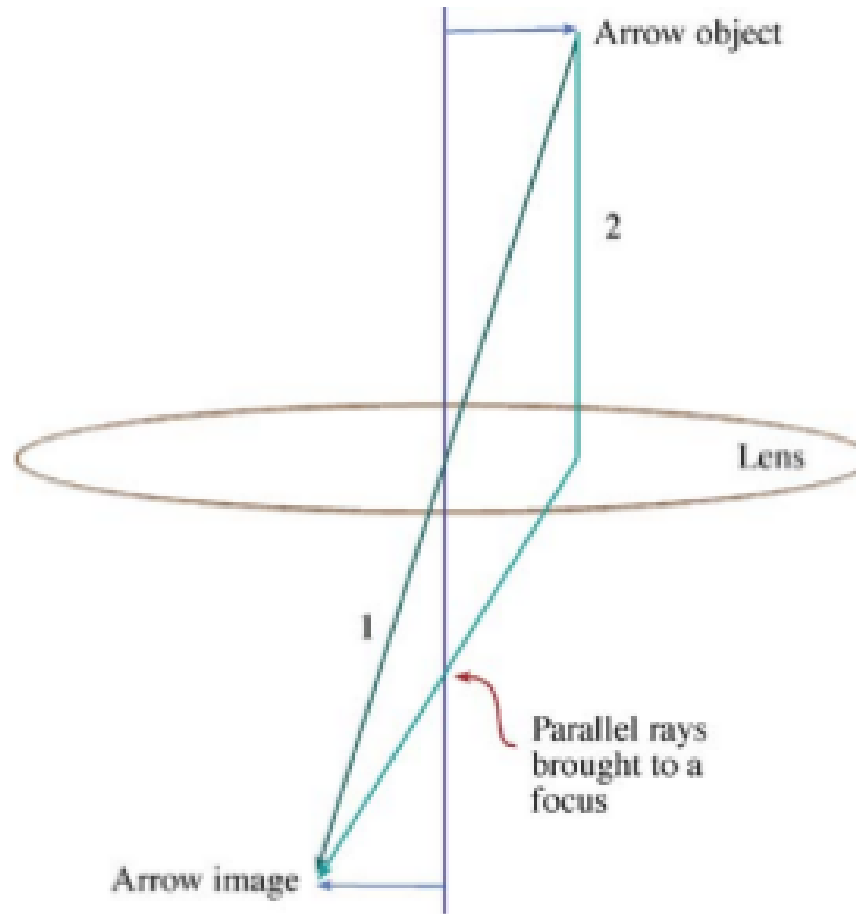
$$E_k = \frac{1}{2} m v^2$$

$$E_k = \frac{p^2}{2m}$$

$$U = 300 \text{ kV} \Rightarrow \lambda = 1.97 \text{ pm}$$

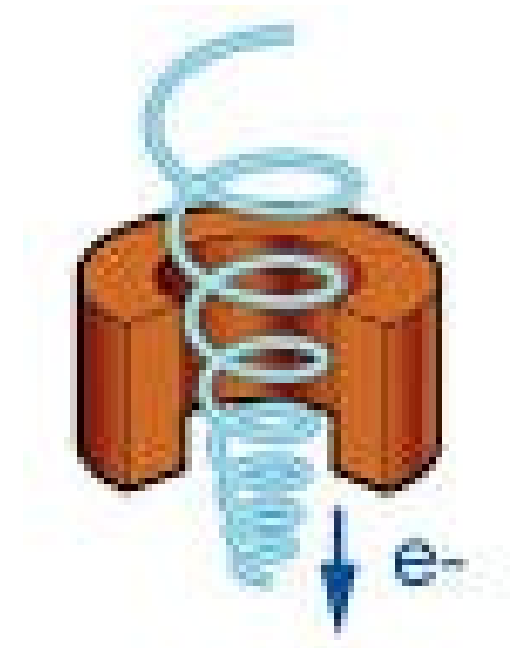
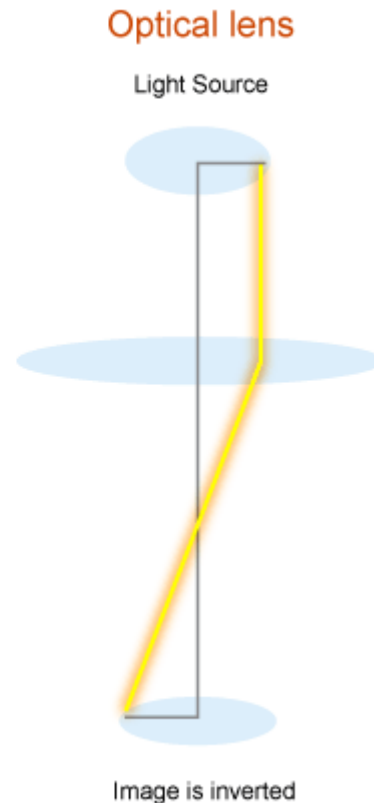
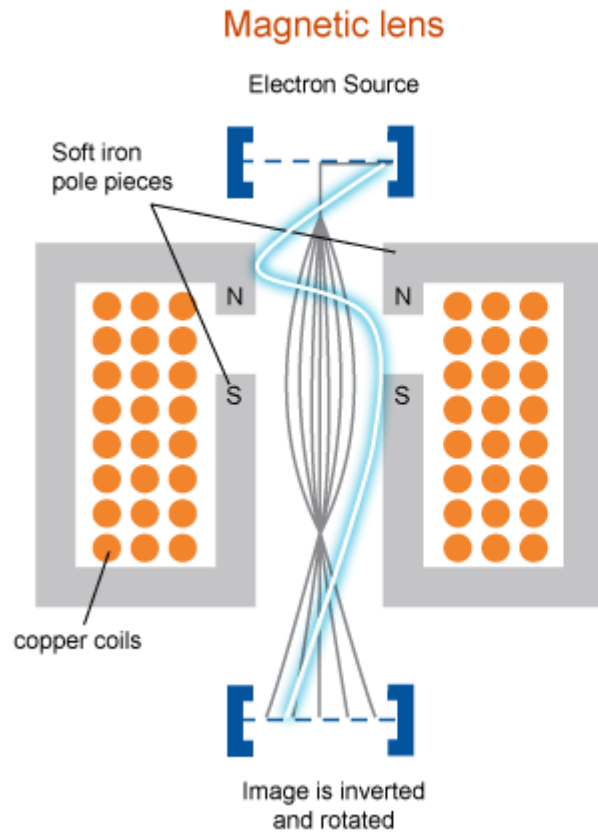
$$U = 200 \text{ kV} \text{ ??}$$

Lenses – ray diagram



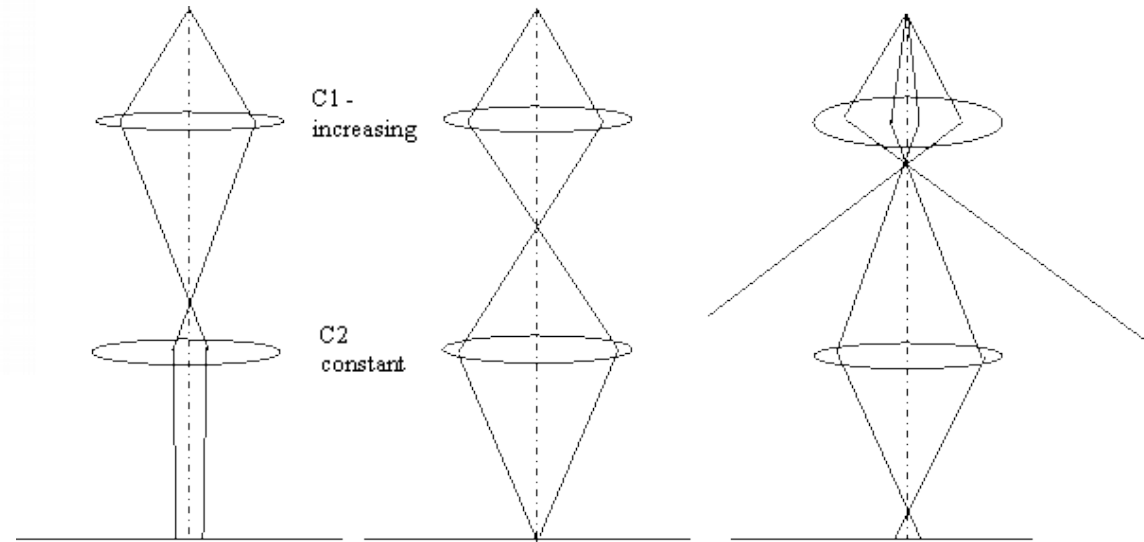
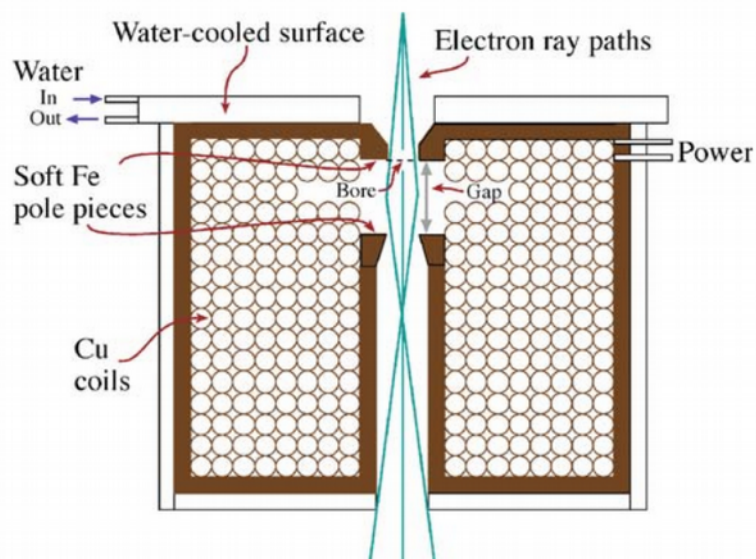
Electromagnetic lenses

Lorentz force: $\mathbf{F} = q(\mathbf{E} + \mathbf{v} \times \mathbf{B})$



Magnetic lenses rotate image

Electromagnetic lenses



Power of the magnetic lens can be changed

Electromagnetic lenses

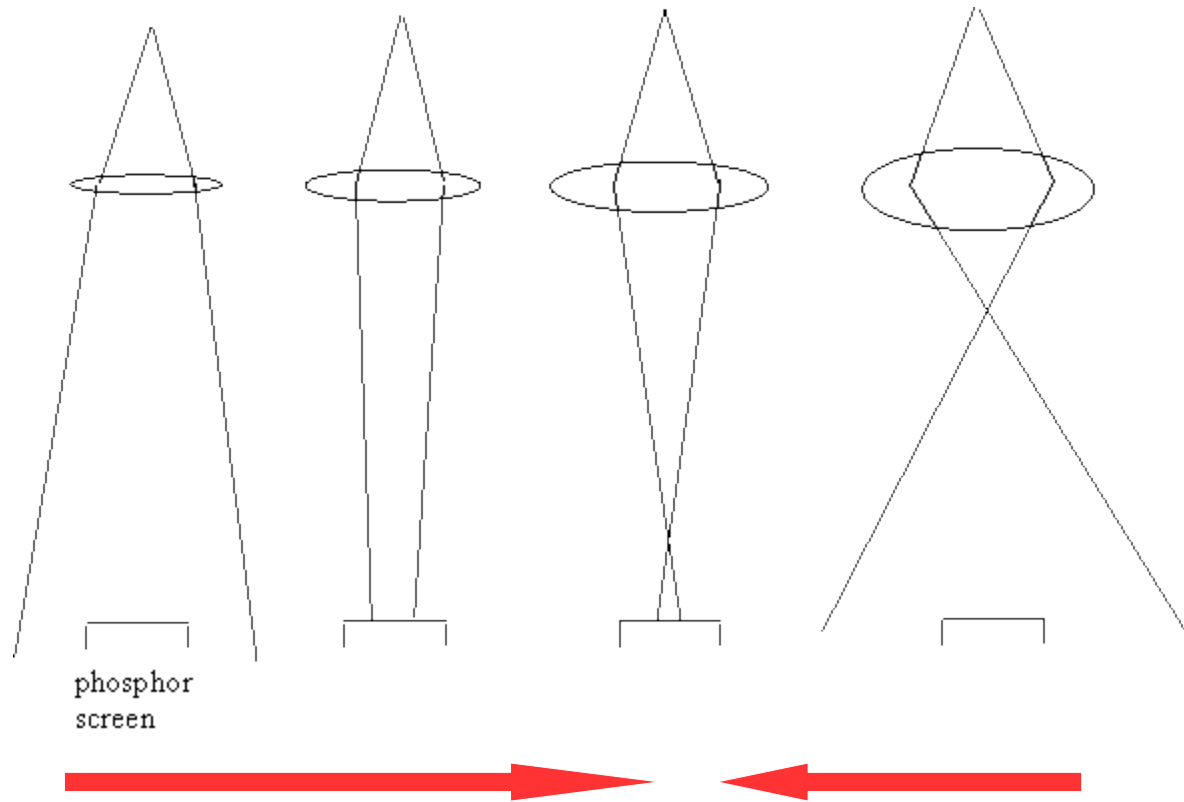
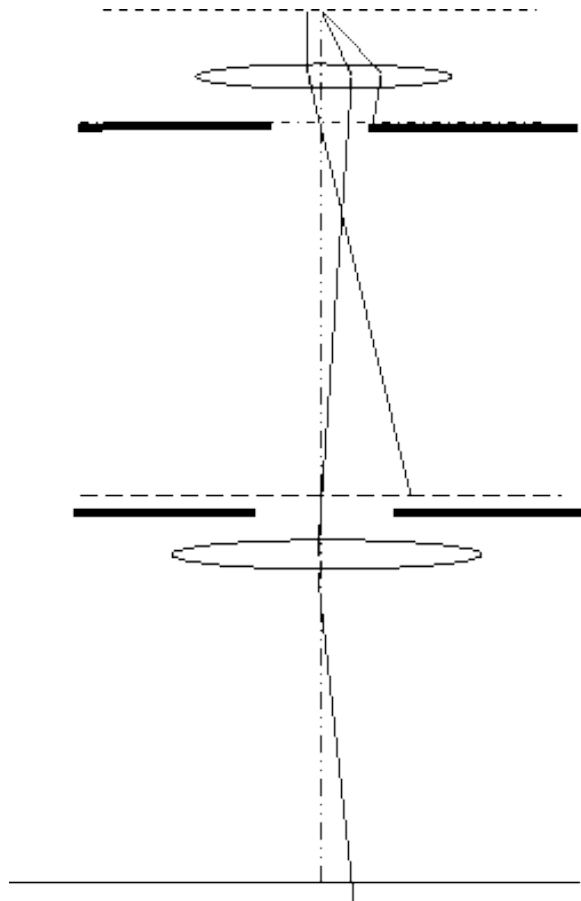
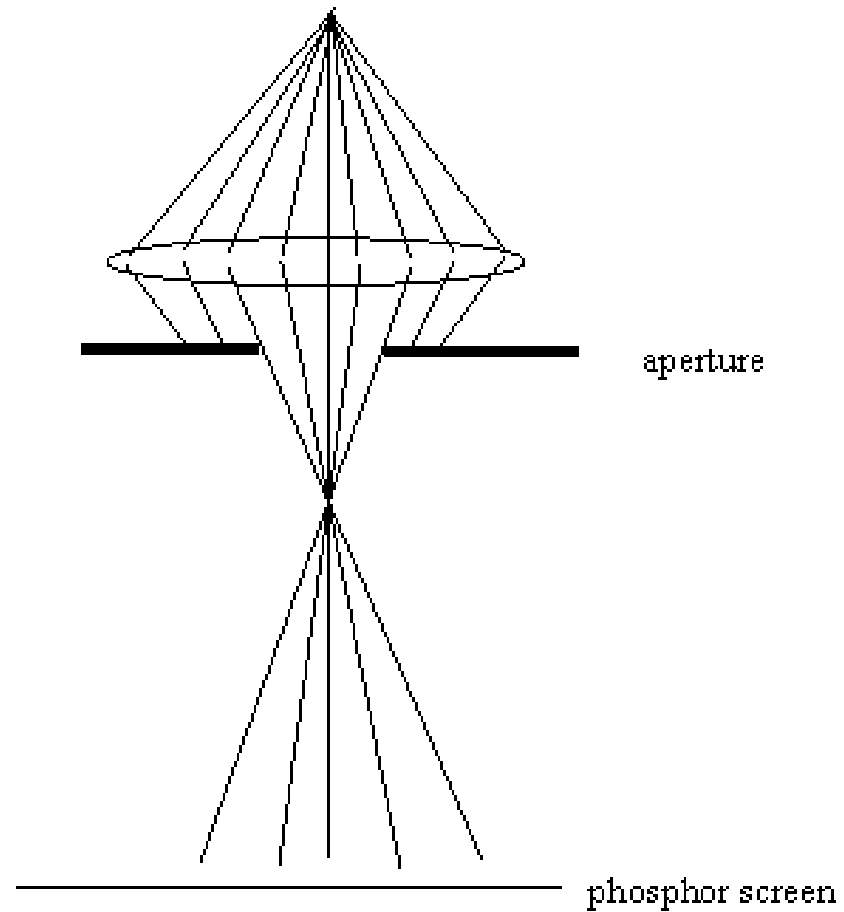


Illustration on the detector changes with change of lens power

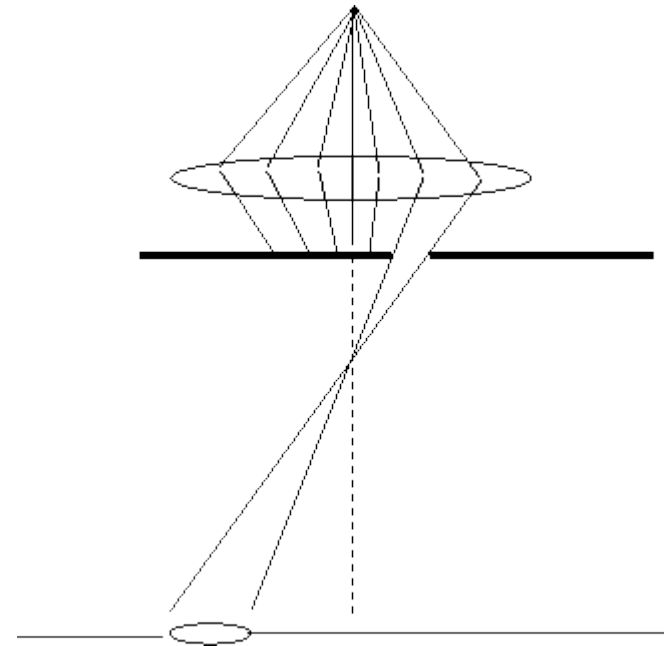
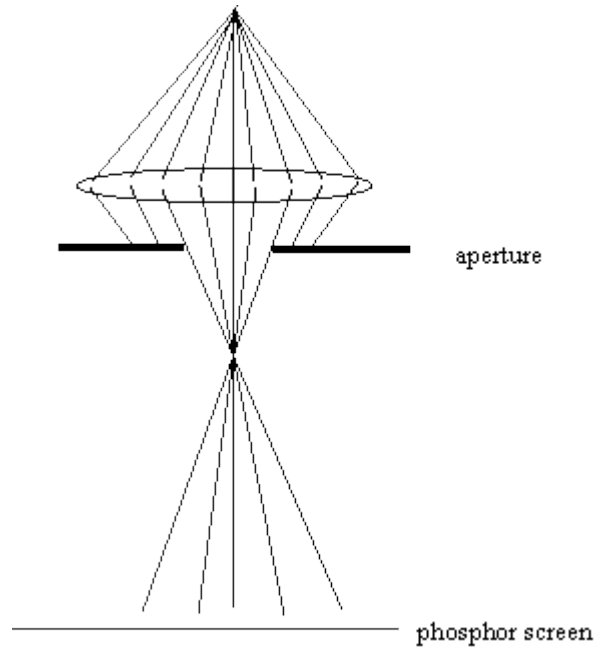
Lens assembly - apertures



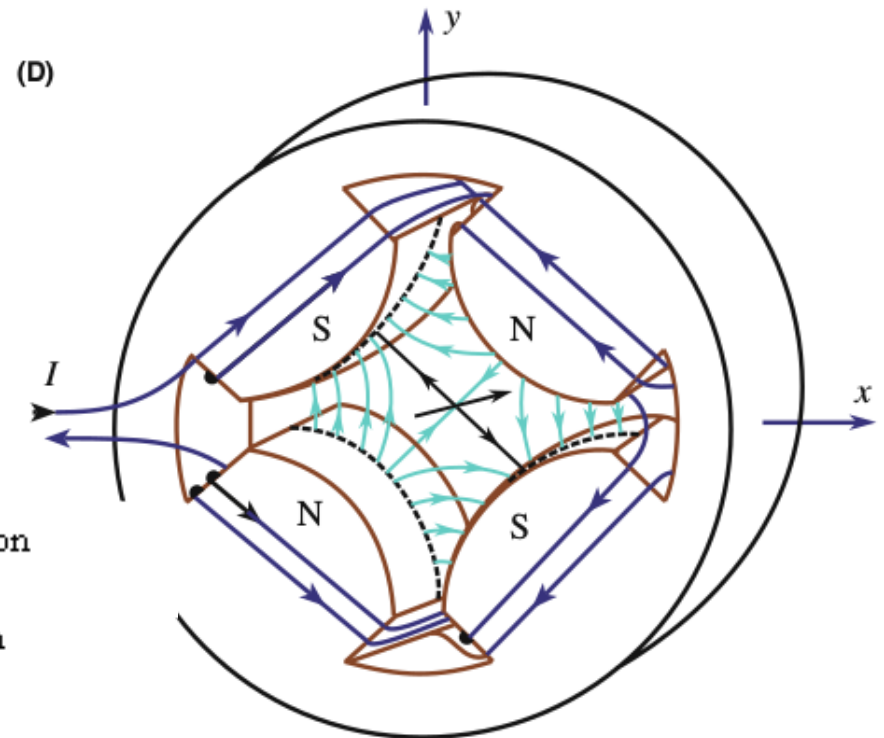
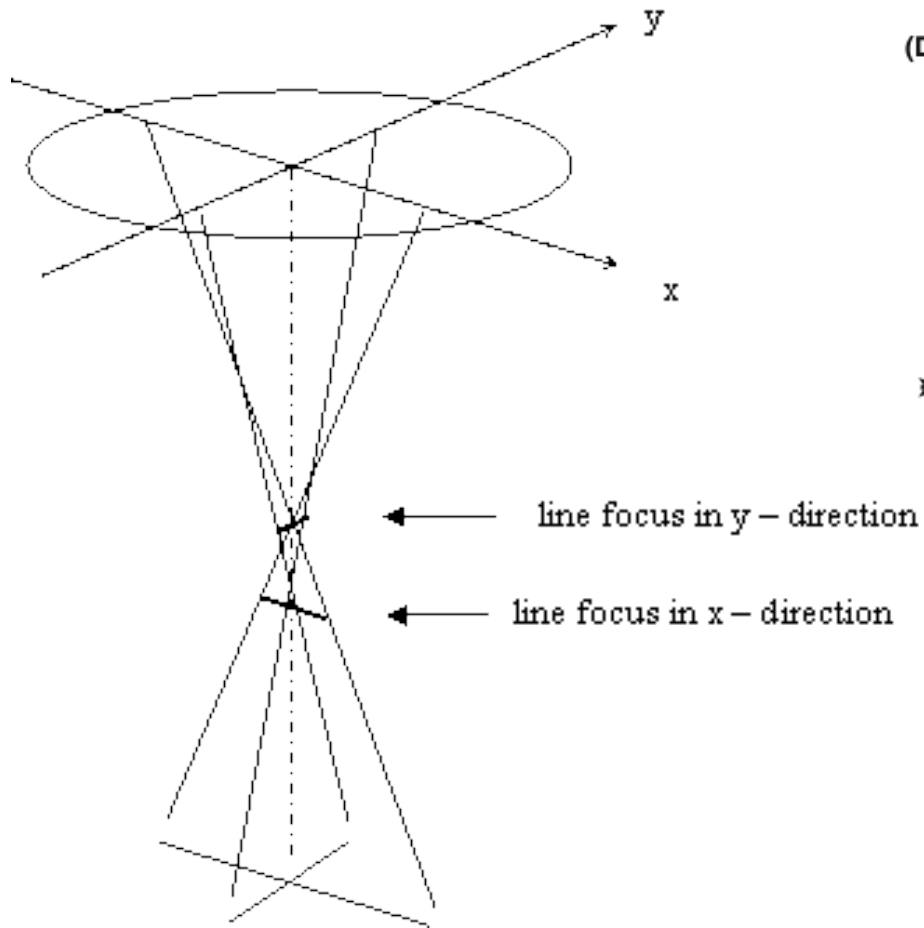
Aperture size: ~100um



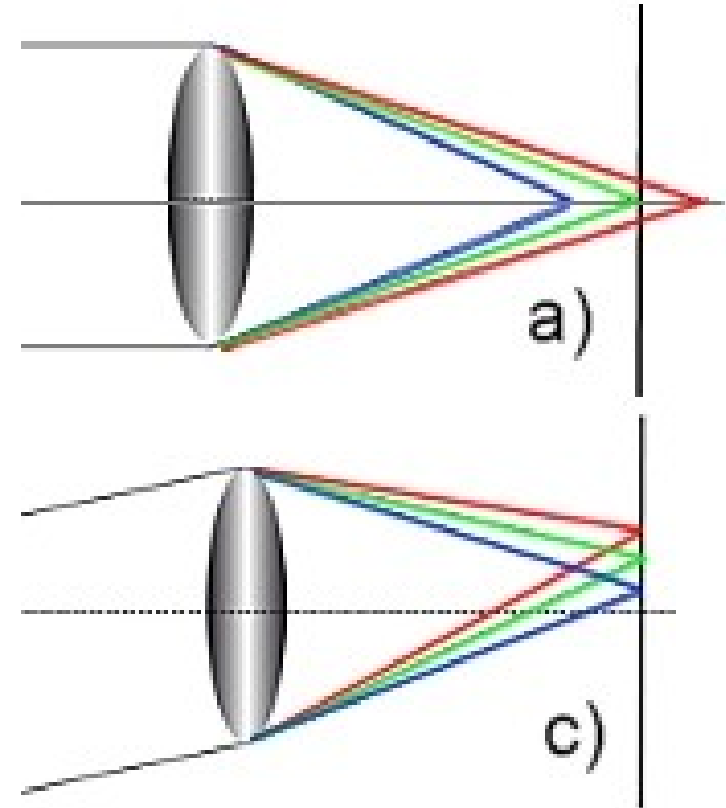
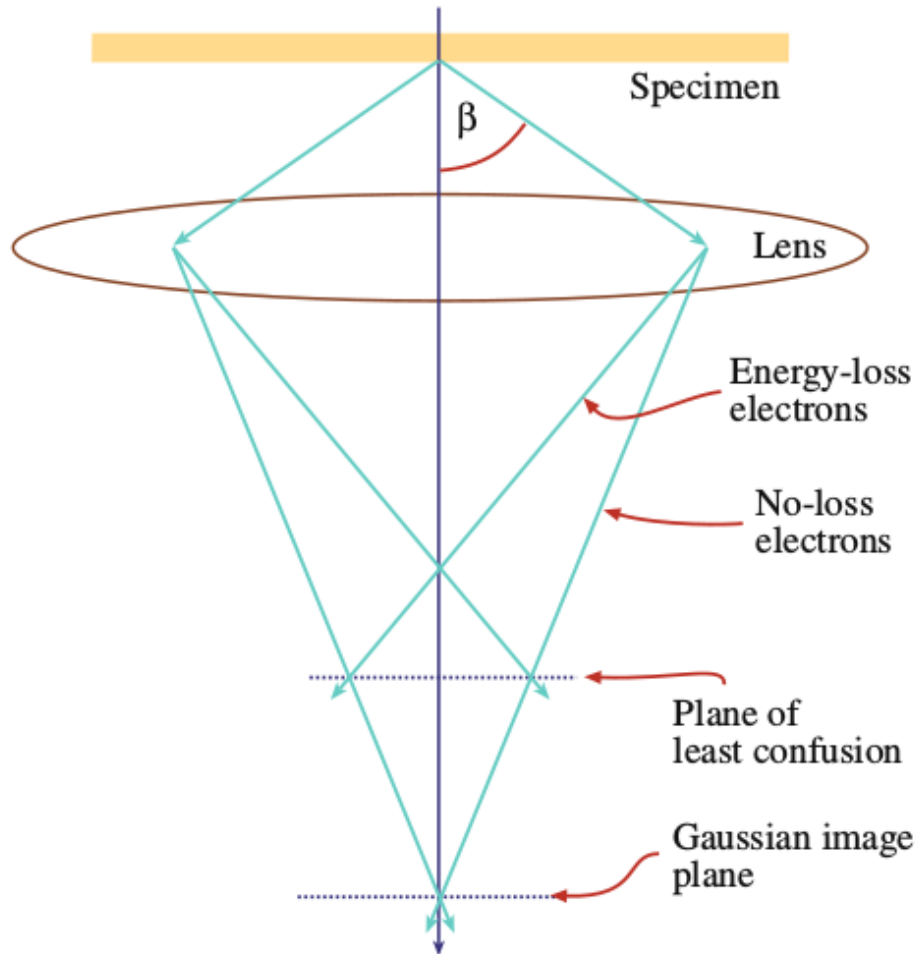
Lens assembly - apertures



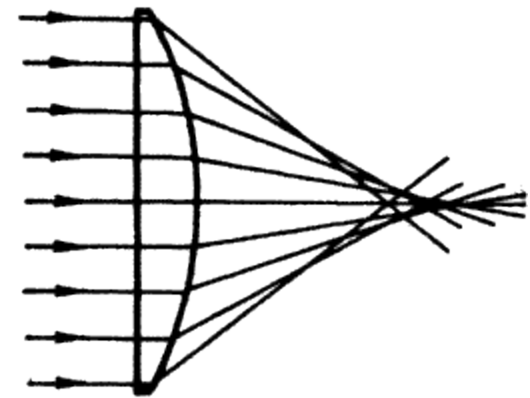
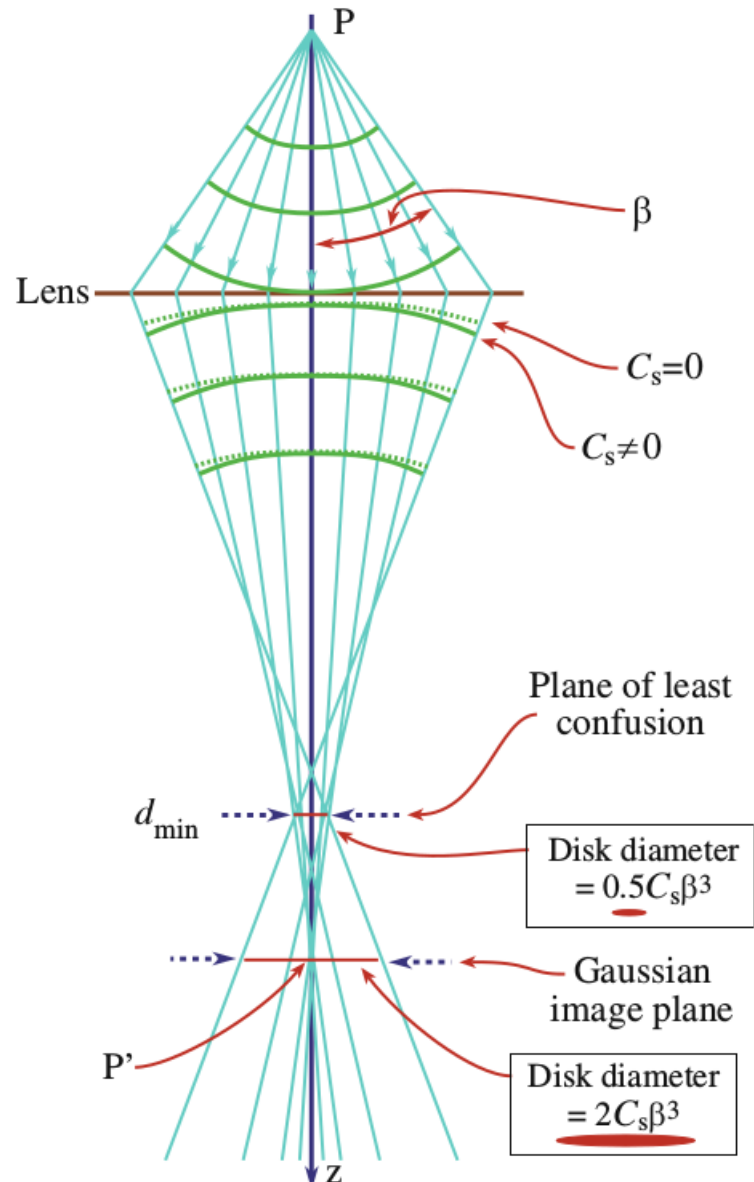
Lens assembly - stigmators



Lens aberrations - chromatic

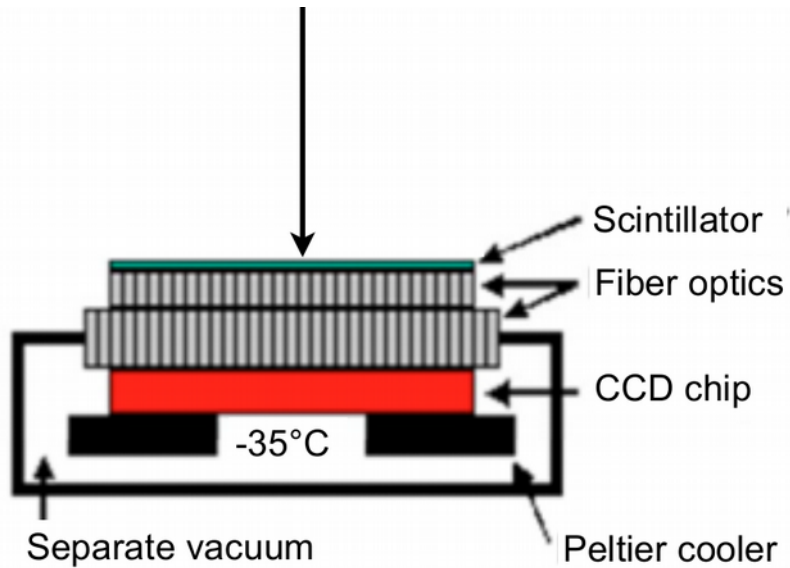


Lens aberrations - spherical

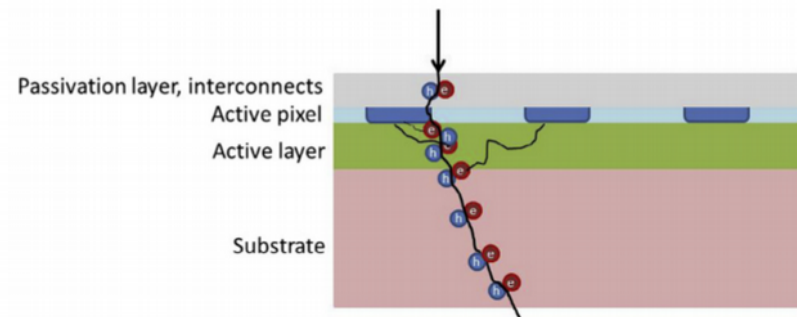
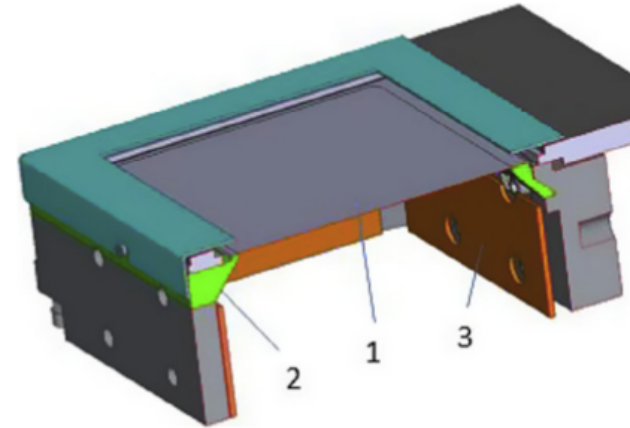


(a)

Detectors



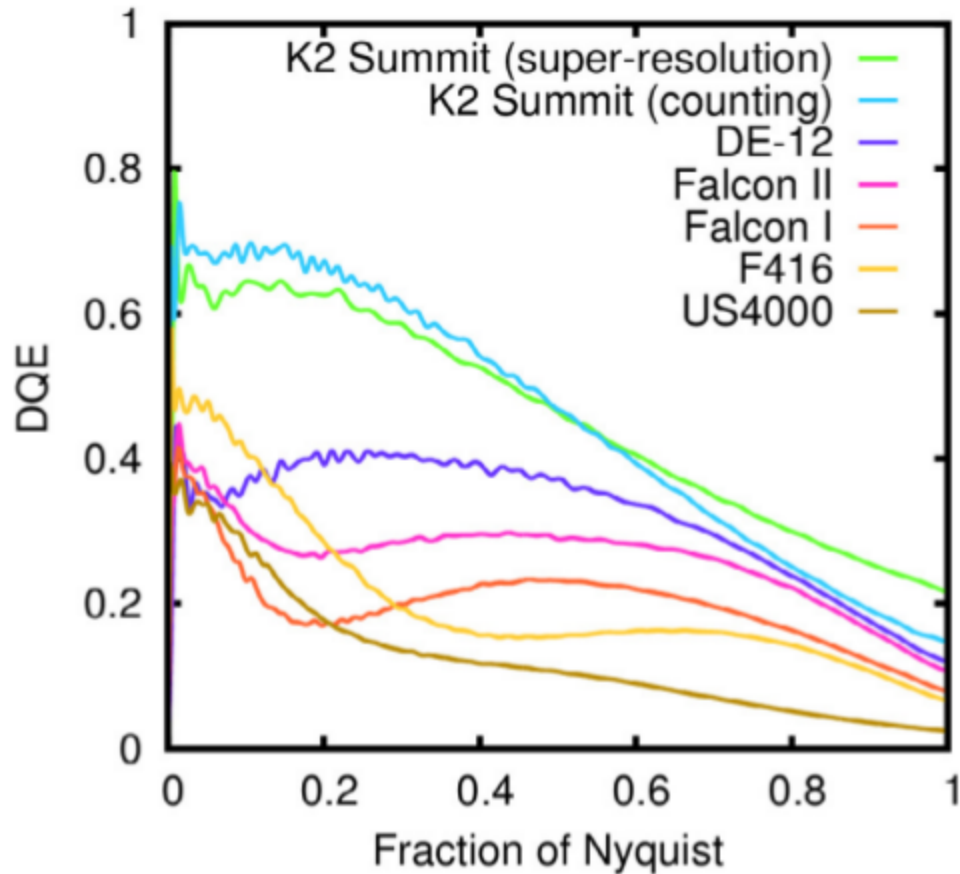
CCD – charge coupled device



CMOS – complementary metal oxide semiconductor

Detectors

DQE – detective quantum efficiency

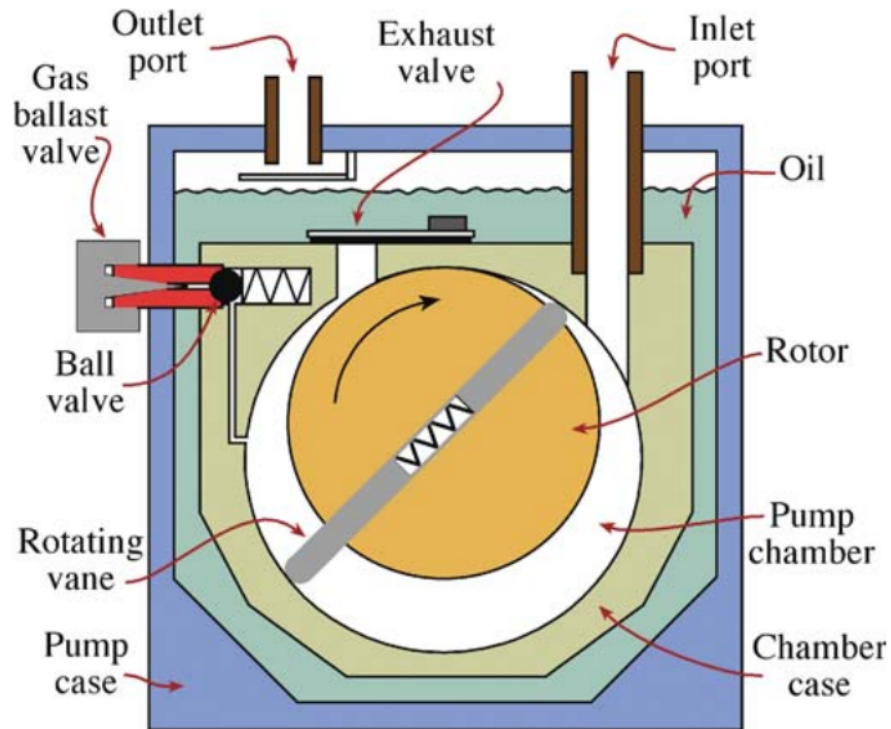


- probability to detect an electron

- $DQE \sim \sin(x)/x$

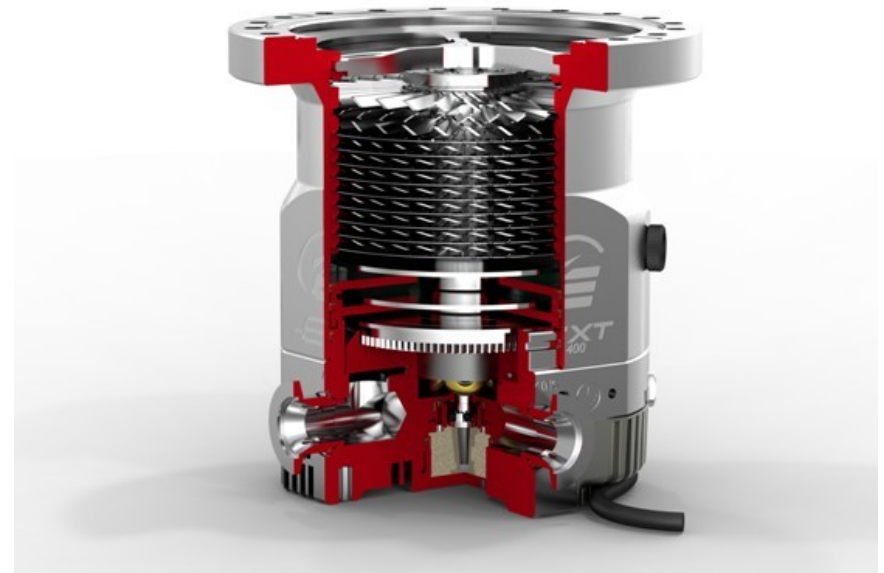
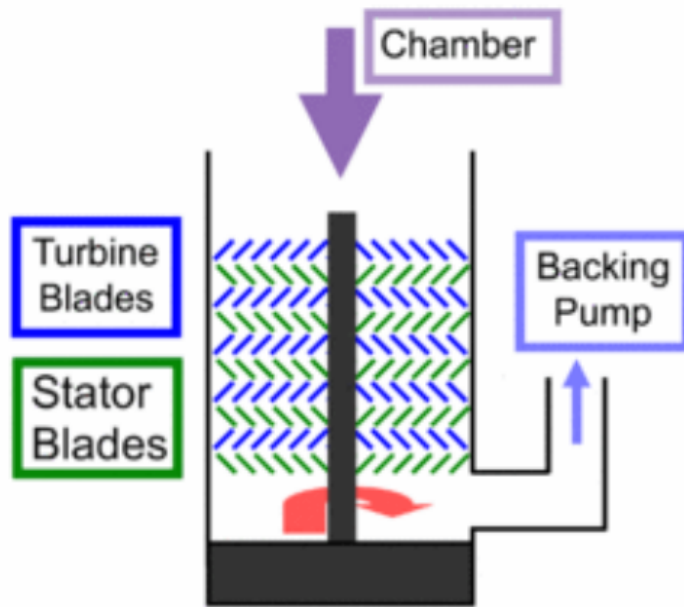
Vacuum system

- roughing pump ($10^5 - 10^{-4}$ Pa)
- turbo molecular pump ($10^{-2} - 10^{-8}$ Pa)
- ion getter pump (up to 10^{-9} Pa)



Vacuum system

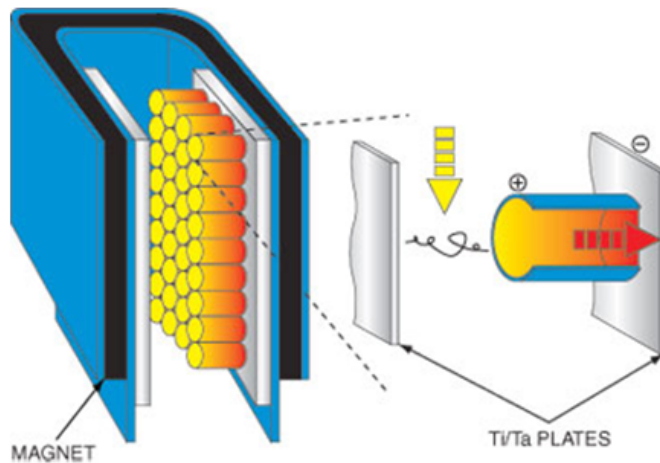
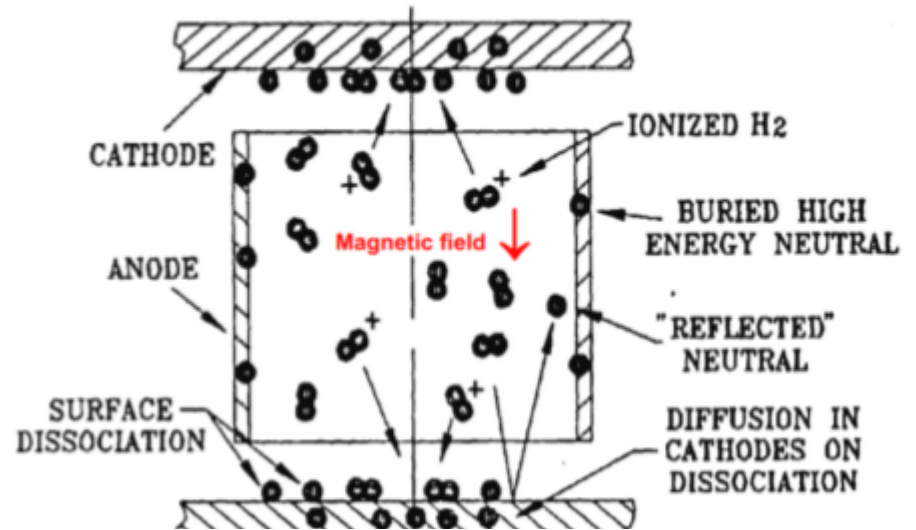
- roughing pump ($10^5 - 10^{-4}$ Pa)
- turbo molecular pump ($10^{-2} - 10^{-8}$ Pa)
- ion getter pump (up to 10^{-9} Pa)



90.000 rpm

Vacuum system

- roughing pump ($10^5 - 10^{-4}$ Pa)
- turbo molecular pump ($10^{-2} - 10^{-8}$ Pa)
- ion getter pump (up to 10^{-9} Pa)

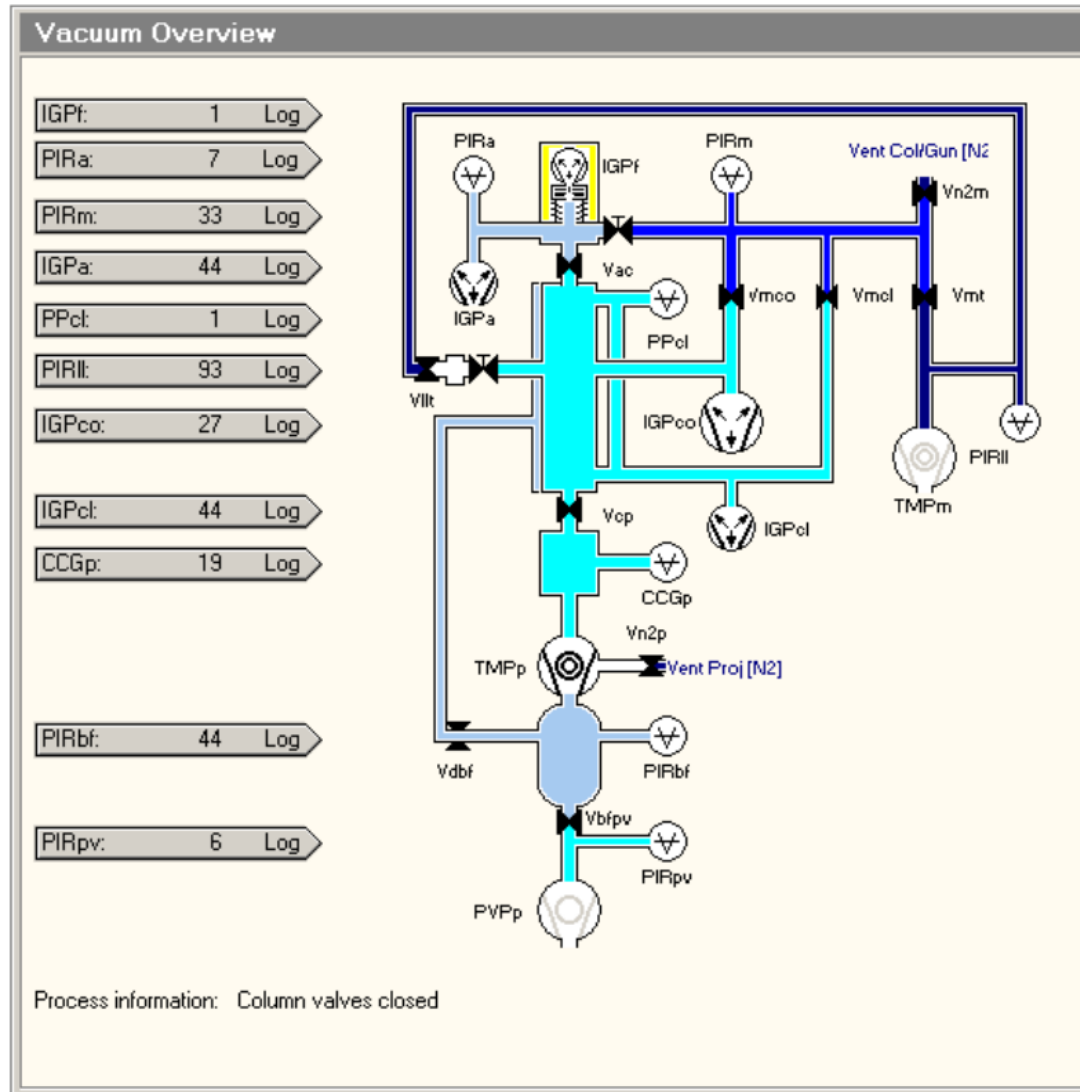


Principle of Operation

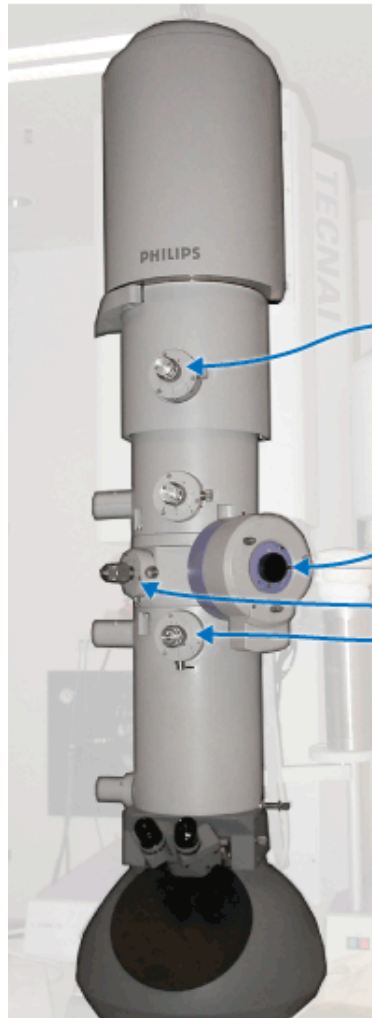


External View

Vacuum system

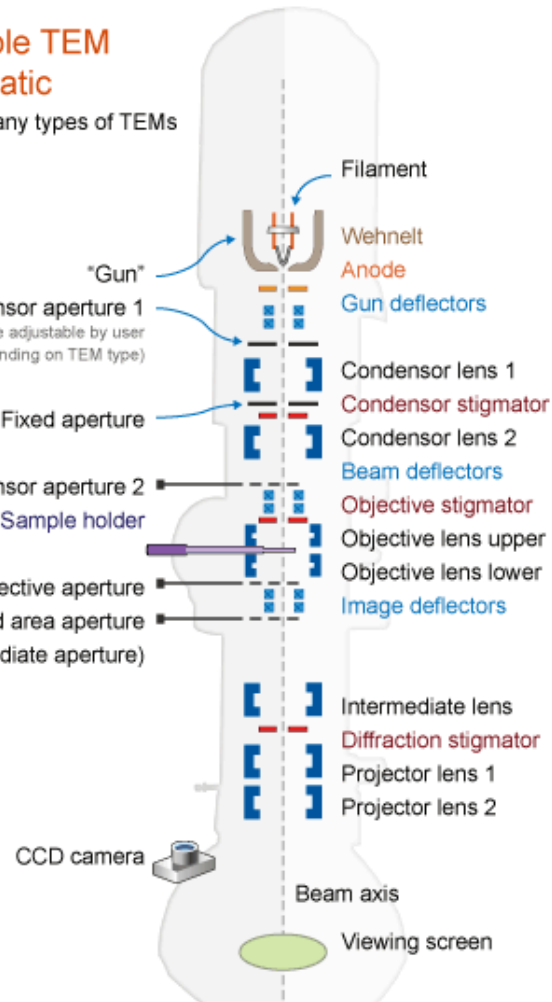


TEM

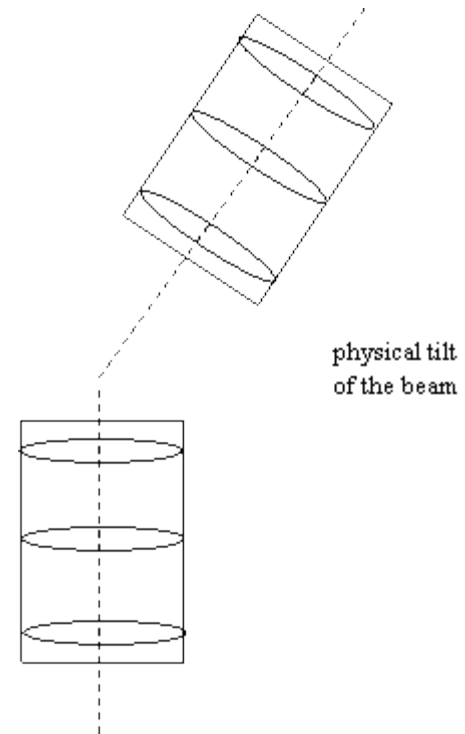
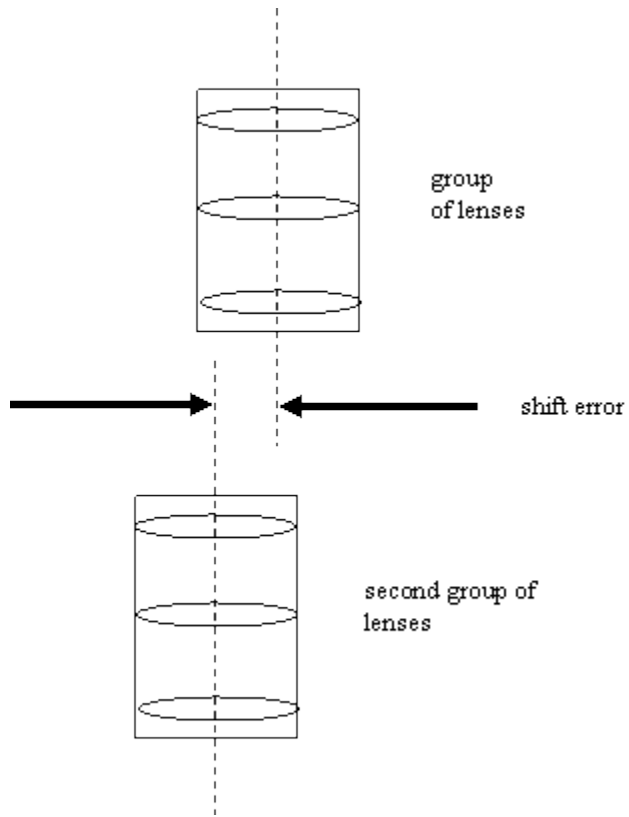


Example TEM schematic

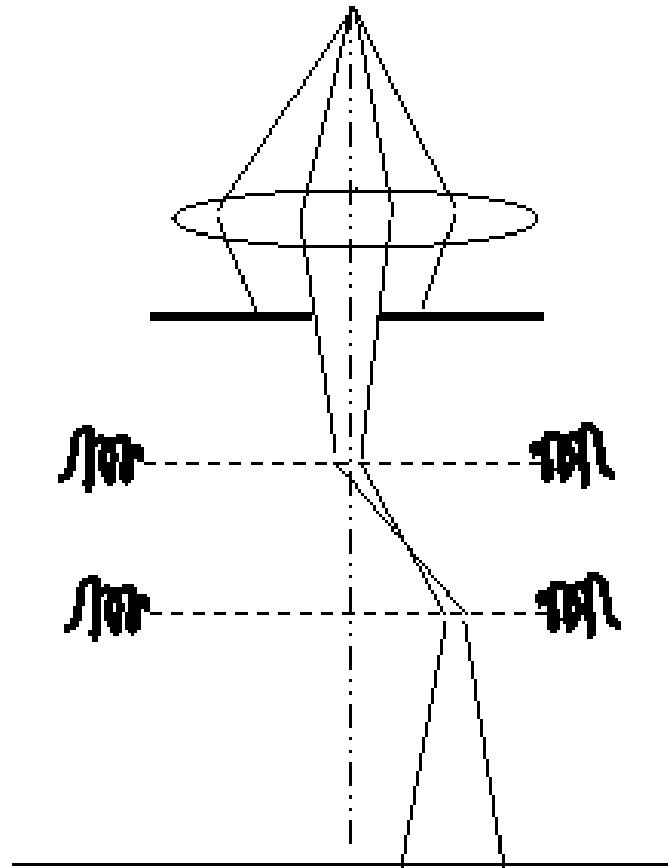
One of many types of TEMs



TEM

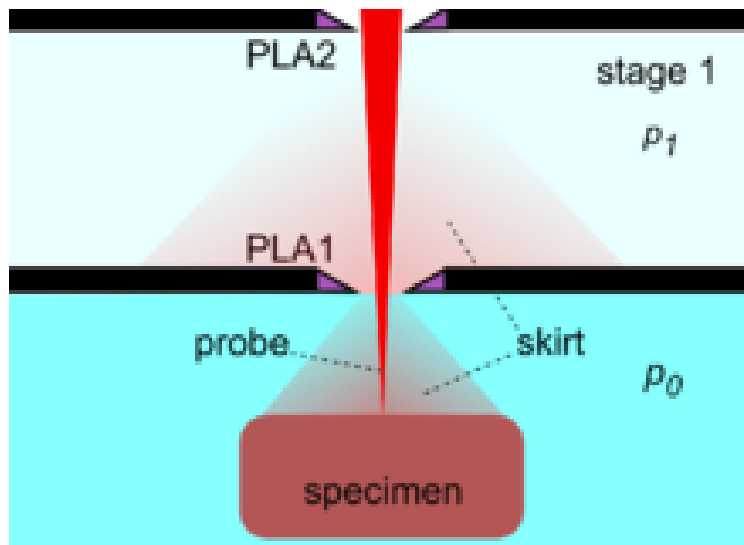


TEM

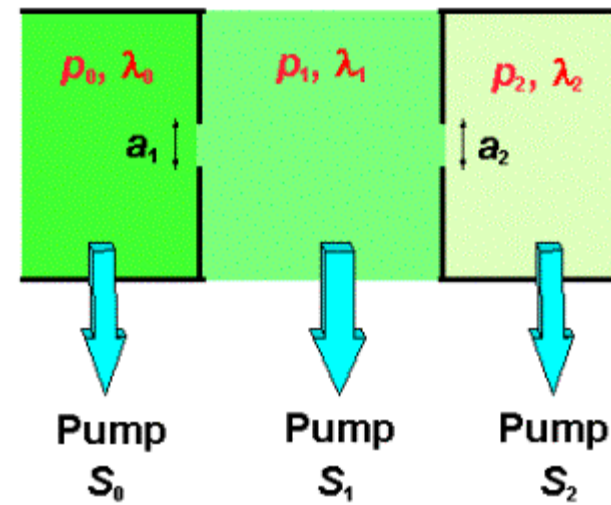


TEM

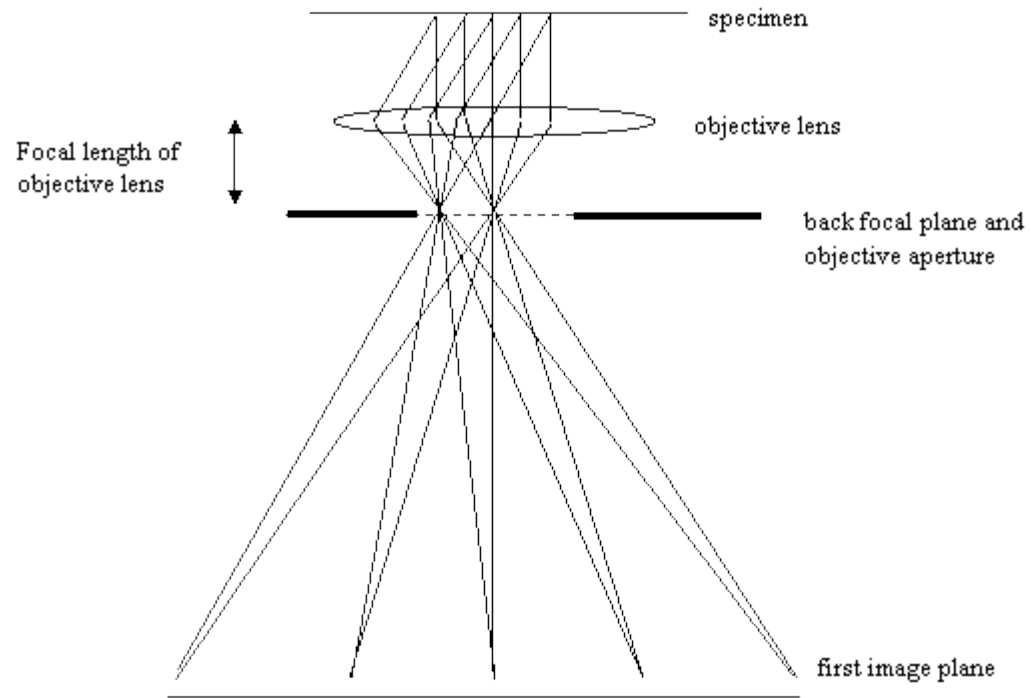
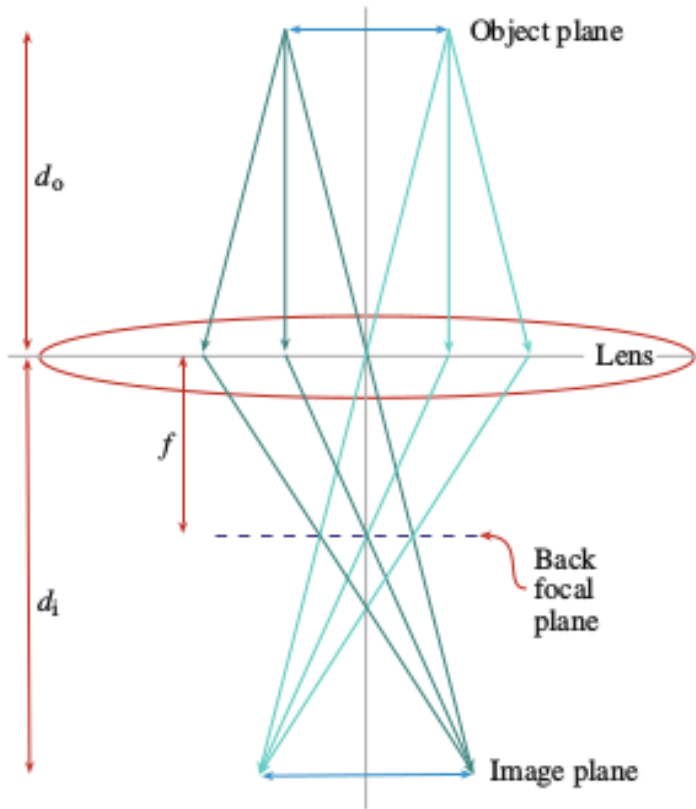
Differential pumping aperture



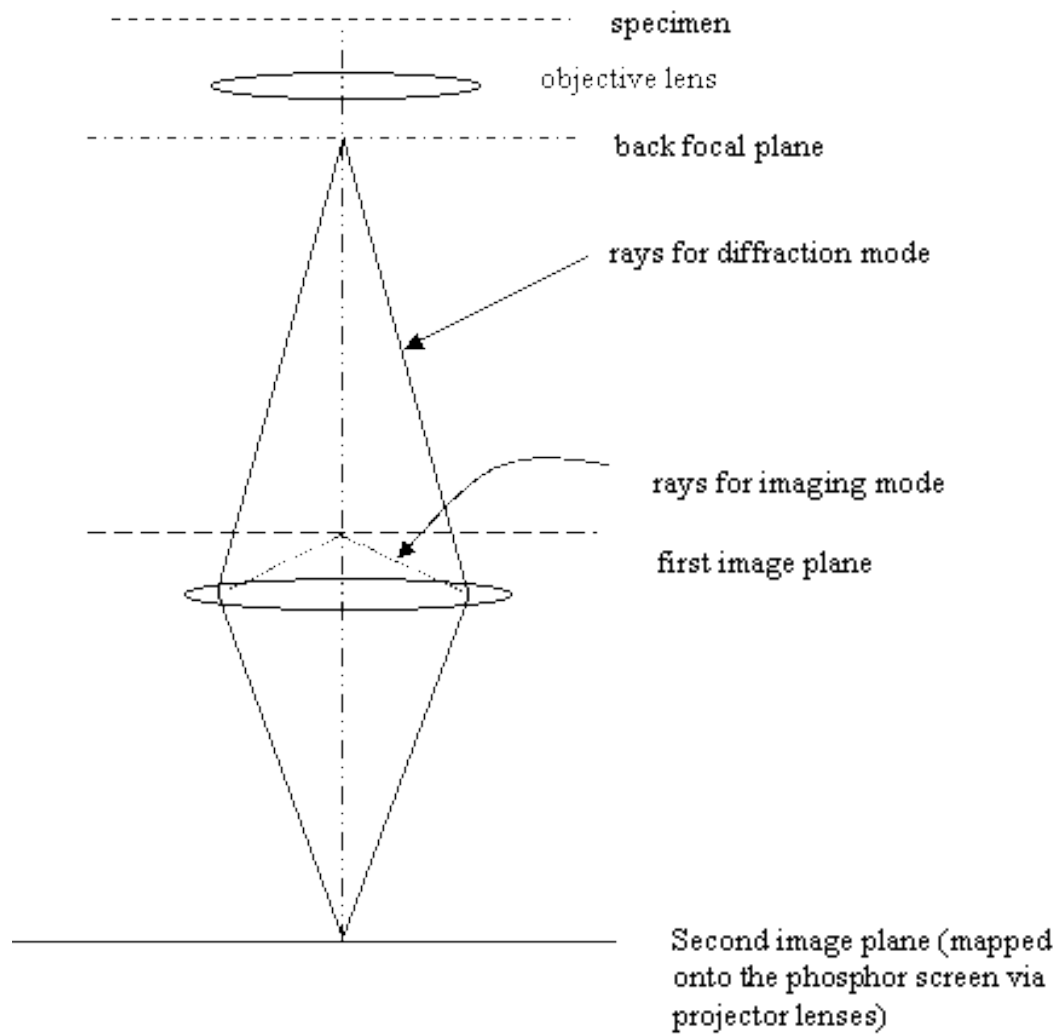
High pressure chamber low pressure 1st stage very low pressure 2nd stage



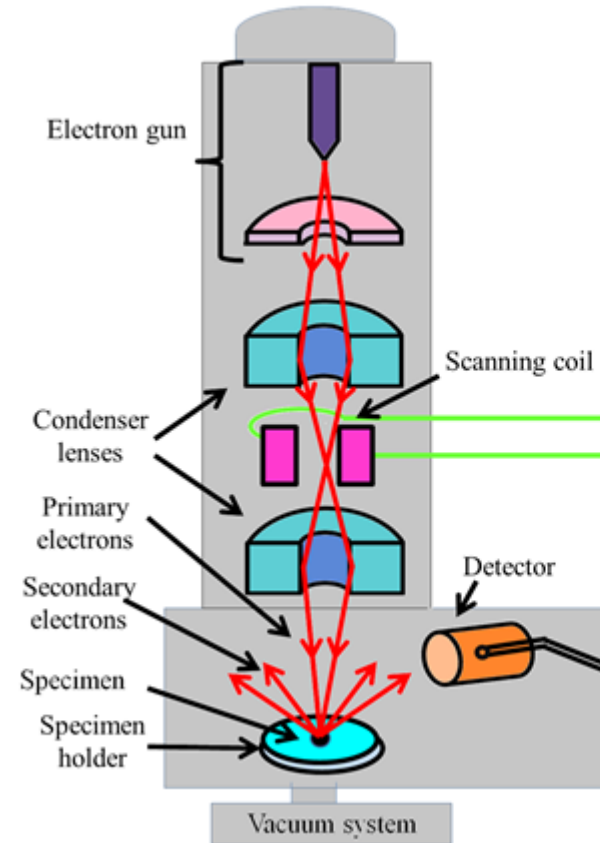
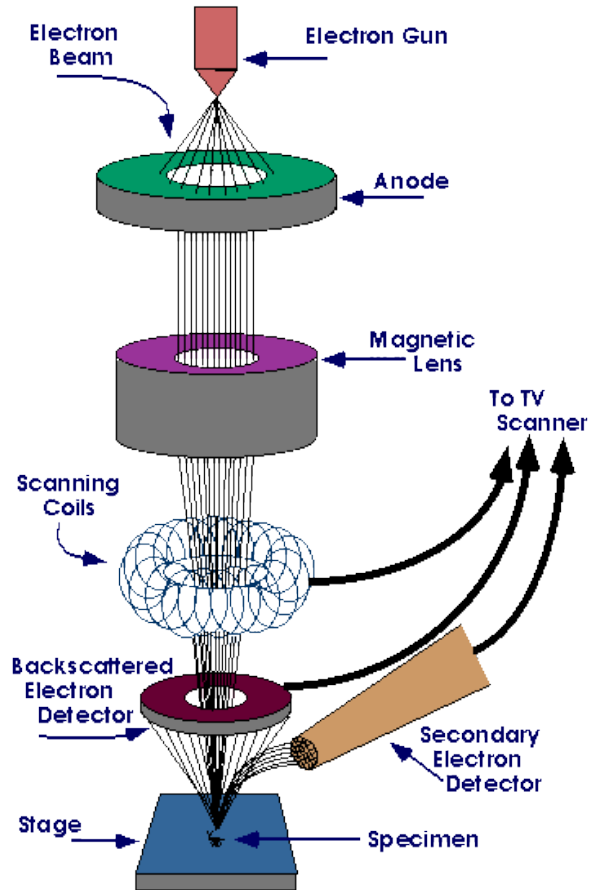
TEM



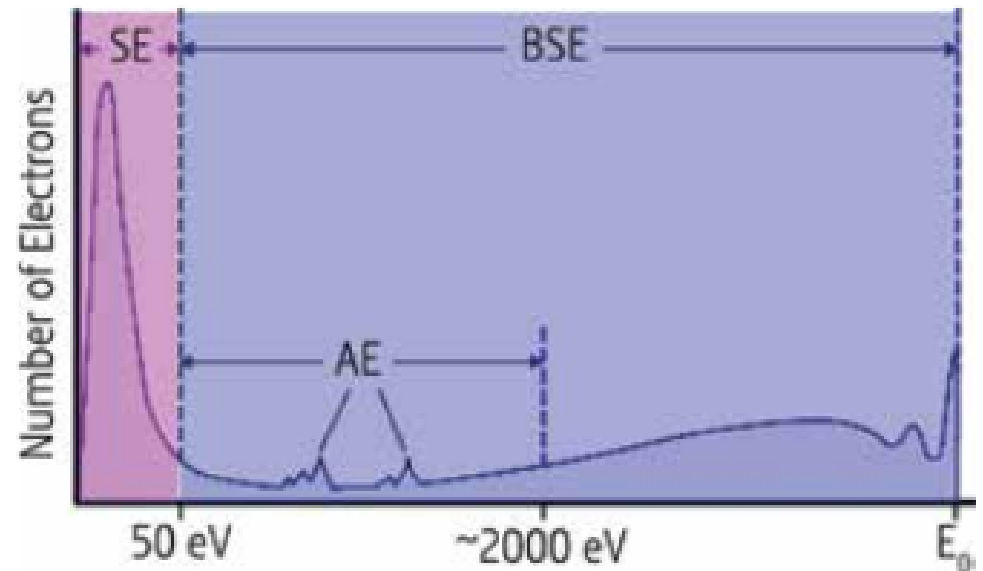
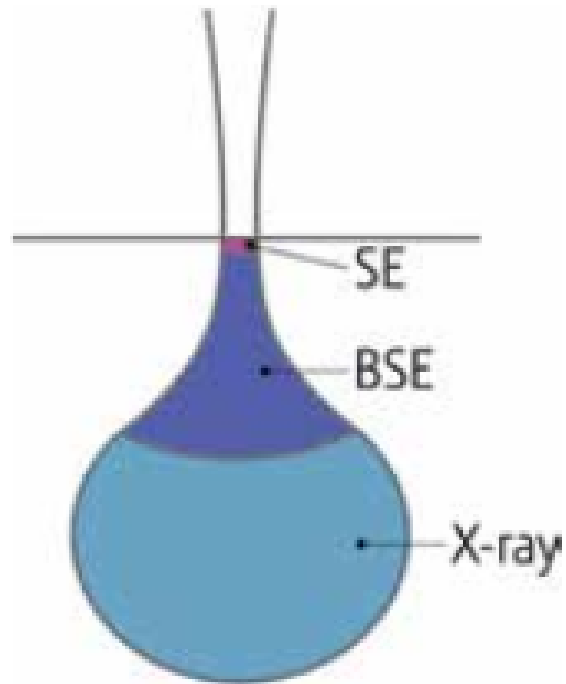
TEM



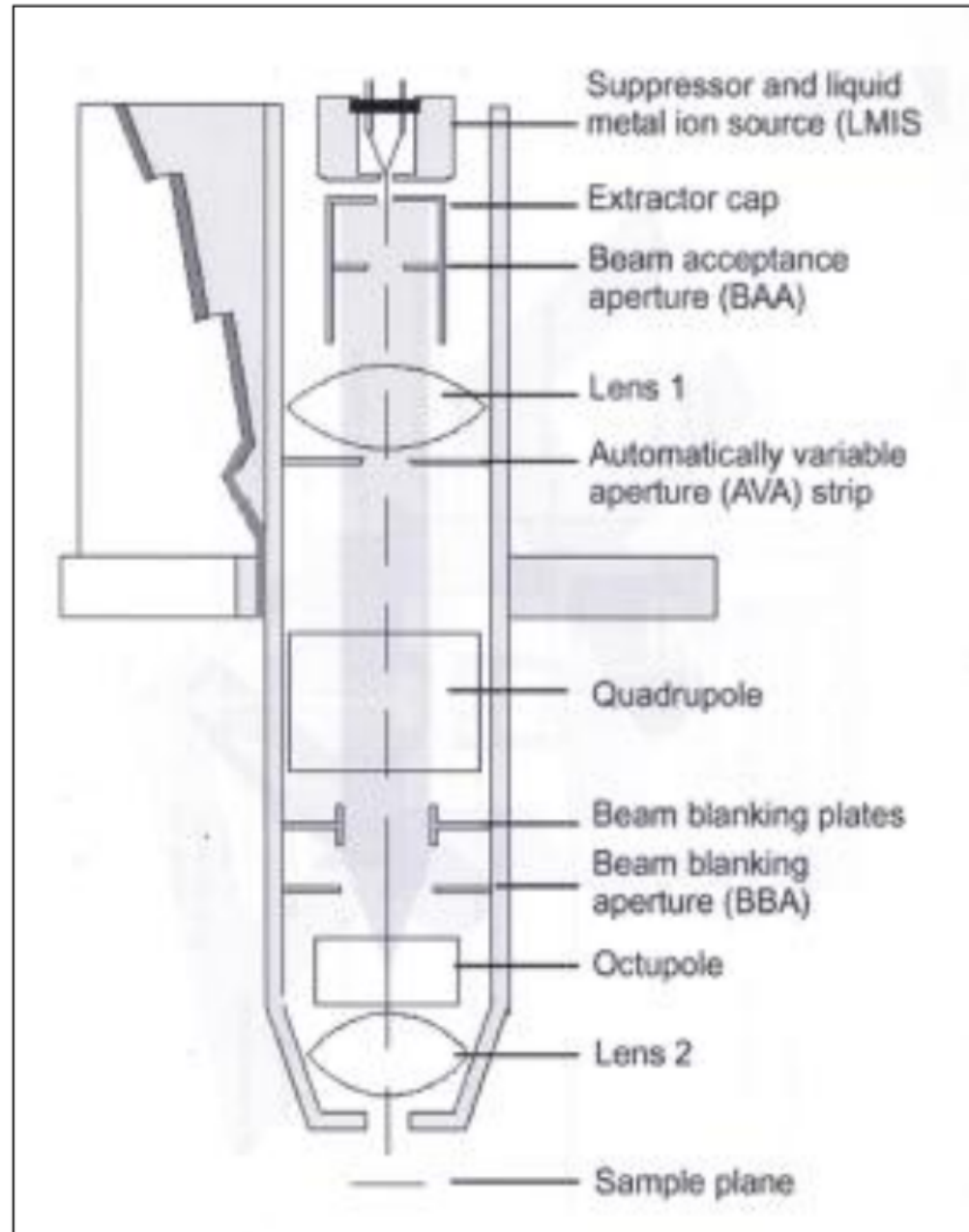
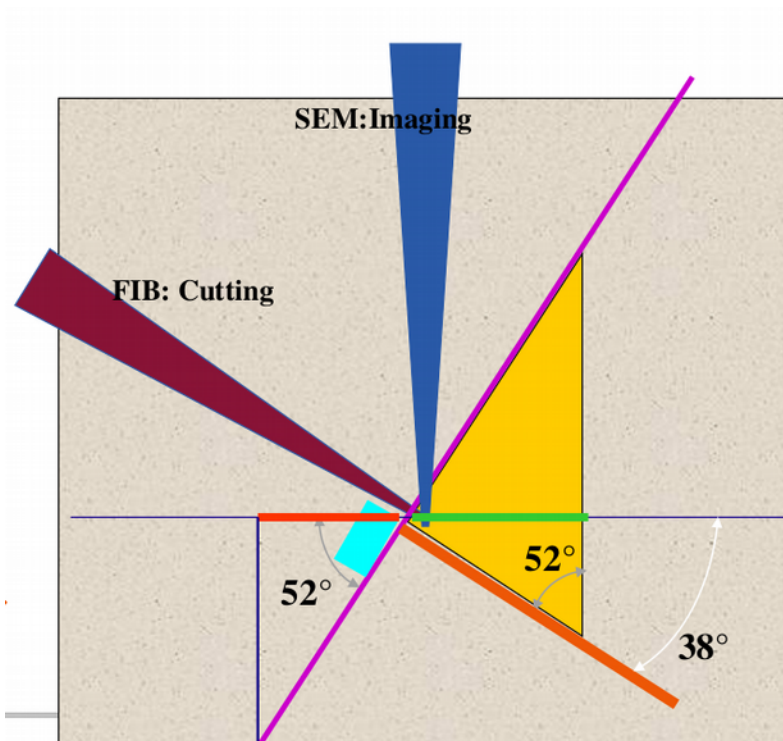
SEM



SEM

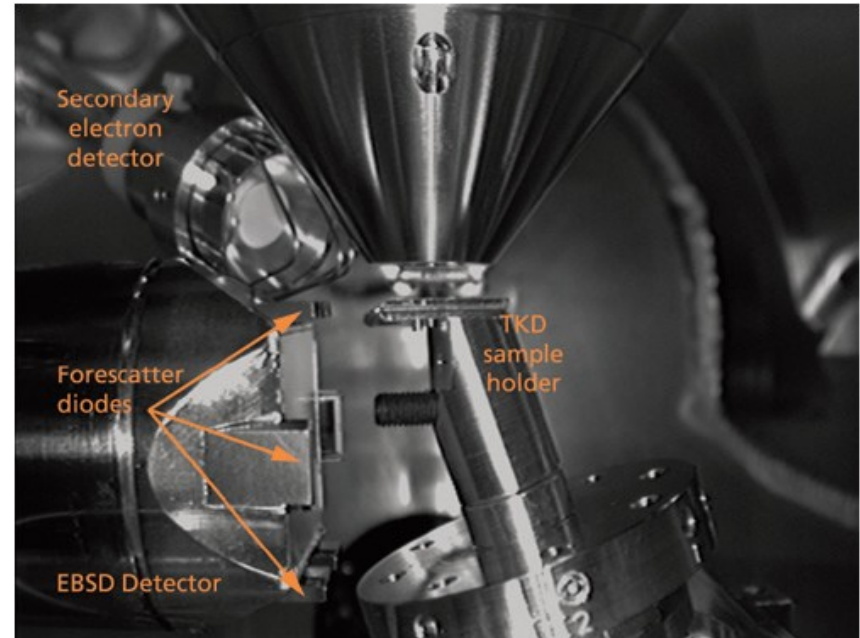
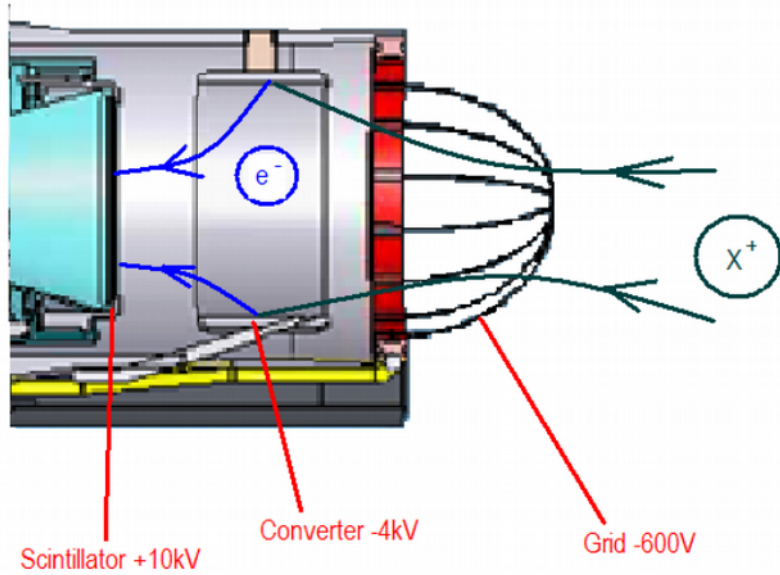


Dual beam FIB/SEM



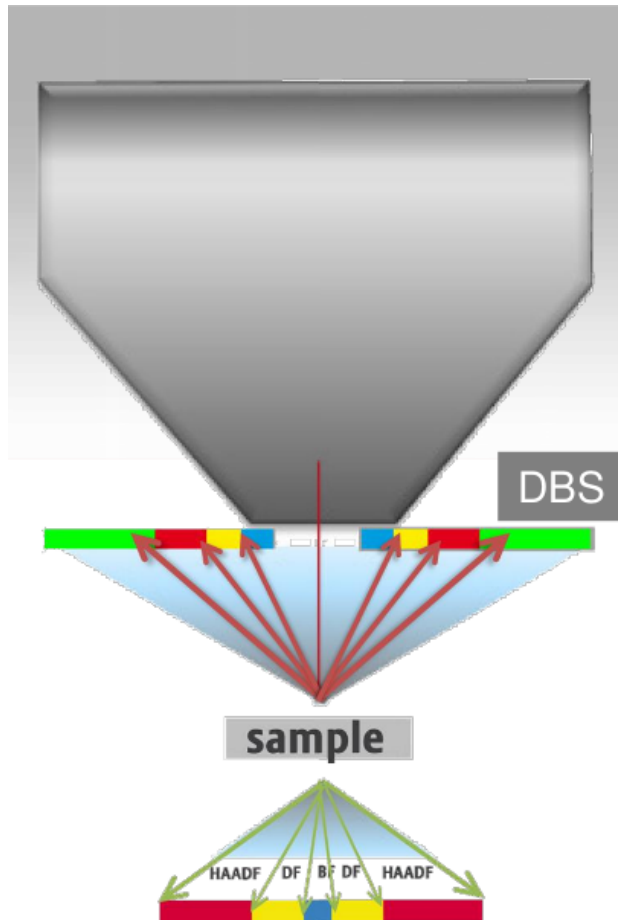
SEM - detection

- Everhart-Thornley Detector (ETD)
- Ion Conversion to Electron Detector (ICE)



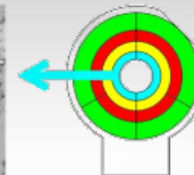
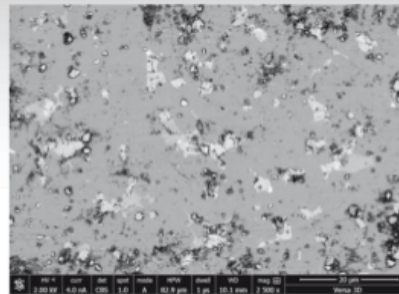
SEM - detection

- Concentric Backscatter detector



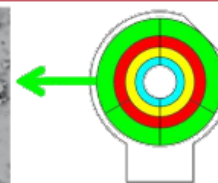
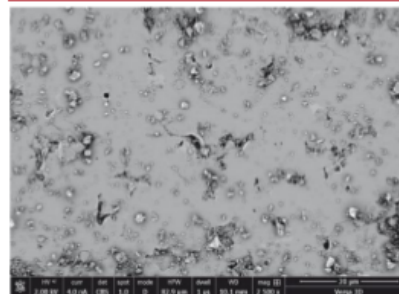
The Directional Backscatter Electron detector* (DBS) allows collection of surface or compositional information through a Concentric Backscatter mode (CBS) to filter signal from various angles (which can be selected by segment, working distance and/or Beam Deceleration*). A range of angles can be precisely selected based on imaging conditions to reveal unique information.

Composition and material contrast



Inner rings collect signal on-axis with the primary beam which contains most channeling or atomic contrast information.

Surface information and topographic contrast



Outer rings collect large angle BSE signal, containing mostly topographic information